Suppression of the superconducting transition of $R\text{FeAsO}_{1-x}\text{F}_x$ **(** $R = Th$ **, Dy, and Ho)**

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A suppression of superconductivity in the late rare-earth *R*FeAsO1−*x*F*^x* materials is reported. The maximum critical temperature (T_c) decreases from 51 K for *R*=Tb to 36 K for HoFeAsO_{0.9}F_{0.1}, which has been synthesized under 10 GPa pressure. This suppression is driven by a decrease in the Fe-As-Fe angle below an optimum value of 110.6°, as the angle decreases linearly with unit-cell volume *(V)* across the $RFeAsO_{1-x}F_x$ series. A crossover in electronic structure around this optimum geometry is evidenced by a change in sign of the compositional dT_c/dV , from negative values for previously reported large *R* materials to positive for $HoFeAsO_{0.9}F_{0.1}$.

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Rare earth (R) oxypnictides RFeAsO (Ref. [1](#page-3-1)) were recently discovered to superconduct when doped, with critical temperatures surpassed only by the high- T_c cuprates. Several families of superconducting iron pnictides have subsequently been discovered.² These all have layered structures containing AsFeAs slabs with Fe tetrahedrally coordinated by As. The main types are the 1111 materials based on *R*FeAsO or $MFeAsF (M=Ca, Sr, Ba)$, the 122 phases $MFe₂As₂$, and the 111 *A*FeAs $(A = Li, Na)$ family. The related binaries Fe*X* $(X$ =Se, Te) are also superconducting.

The electron-doped 1111 materials *R*FeAsO_{1−*x*}F_{*x*} and *RFeAsO*_{1− δ} materials remain prominent as they have the highest T_c 's, up to 56 K, and allow lattice and doping effects to be investigated through variations in the R^{3+} cation size and the anion composition. A strong lattice effect is evident at the start of the rare-earth series, as T_c rises from 26 K for LaFeAsO_{1−*x*}F_{*x*} to [4](#page-3-4)3 K under pressure,^{3,4} and to a nearconstant maximum 50–56 K in the $RFeAsO_{1-x}F_x$ and *R*FeAsO_{1−δ} series for *R*=Pr to Gd,^{5[–10](#page-3-6)} but whether lattice effects ultimately enhance or suppress superconductivity for the late *R*'s has been unclear. The late rare-earth $RFeAsO_{1-x}F_x$ materials and the oxygen-deficient $RFeAsO_{1-\delta}$ superconductors require high-pressure synthesis, leading to significant challenges as single phase samples are difficult to prepare, and accurate analyses of cation stoichiometries and O and F contents are difficult. To investigate the effect of the lattice for later *R*, we have synthesized multiple samples of $RFeAsO_{0.9}F_{0.1}$ ($R=Th$, Dy, and Ho) under varying highpressure conditions. Here we report superconductivity in HoFeAsO_{0.9}F_{0.1} for which the maximum T_c of 36 K is markedly lower than in the previous *R* analogs. This is part of a systematic suppression of superconductivity by the smaller, late *R* cations. HoFeAs $O_{0.9}F_{0.1}$ also shows a reversal in the sign of the compositional dT_c/dV (V=unit-cell volume) compared to the early *R* materials, confirming that the decreasing *R* size has a significant effect on the bands contributing to the Fermi surface.

Polycrystalline ceramic *R*FeAsO_{1−*x*}F_{*x*} samples (*R*=Tb, Dy, and Ho) were synthesized by a high-pressure method and investigated by powder x-ray diffraction, magnetization, and conductivity measurements.¹¹ Initial results for $RFeAsO_{1-x}F_x$ $(R = Th$ and Dy) were published elsewhere.¹² Both materials were found to be superconducting with maximum T_c 's of 46 and 45 K, respectively. Little difference in superconducting properties between samples with nominal compositions of $x=0.1$ and 0.2 were observed, and the $x=0.2$ materials were generally of lower phase purity, and so the *x*= 0.1 composition was used in subsequent syntheses. The best samples typically contain $\sim 80\%$ by mass of the superconducting phase with residual nonsuperconducting R_2O_3 and *R*As phases also present. The sample purity and superconducting properties are not sensitive to synthesis pressure over a range that moves to higher pressures as *R* decreases in size; *R* =Tb and Dy superconductors were respectively prepared at 7–10 and 8–12 GPa, heating at $1050-1100$ °C. Repeated syntheses of TbFeAsO_{1−*x*}F_{*x*} gave several samples with higher T_c 's than the above value, the highest value is T_c (max)=5[1](#page-0-0) K (Fig. 1). Further DyFeAsO_{1−*x*}F_{*x*} samples did not show higher transitions than before, so we conclude that T_c (max) in this system is 45 K.

Tetragonal HoFeAs $O_{0.9}F_{0.1}$ was obtained from reactions at 10 GPa pressure and the properties of six $HoFeAsO_{0.9}F_{0.1}$ samples prepared under varying conditions are summarized

FIG. 1. Resistivity and (inset) susceptibility data for an optimum sample of TbFeAsO $_{0.9}F_{0.1}$, showing a sharp superconducting transition at $T_c = 51$ K. The sample was prepared at 7 GPa and 1050 °C.

Sample	t_{synth} (hr)	T_{synth} $(^\circ C)$	a A)	\mathcal{C} (A)	Vol (\AA^3)	T_c (K)	Mass frac. $(\%)$	Diamag. frac. $(\%)$
	2	1150	3.8246(3)	8.254(1)	120.74(3)	29.3	75	70
2	2	1100	3.8272(2)	8.2649(8)	121.06(2)	33.0	74	85
3		1150	3.8258(5)	8.264(2)	120.96(4)	33.2	73	76
$\overline{4}$	3	1100	3.8282(5)	8.261(2)	121.07(5)	33.7	84	74
5	2	1100	3.8282(2)	8.2654(7)	121.13(2)	35.2	81	57
6	2	1100	3.8297(7)	8.270(2)	121.30(7)	36.2	58	46

TABLE I. Synthesis conditions (all samples were synthesized at 10 GPa), refined lattice parameters and volume, T_c 's, mass fractions, and superconducting volume fractions for HoFeAsO_{1−*x*F_{*x*} samples.}

in Table [I.](#page-1-0) Crystal structure refinements and phase analysis were carried out by fitting powder x-ray diffraction data (Fig. 2).^{[13](#page-3-9)} Magnetization measurements demonstrate that all six HoFeAsO_{1−*x*}F_{*x*} samples are bulk superconductors with T_c 's of 29-[3](#page-1-2)6 K (Fig. 3). Resistivities show smooth hightemperature evolutions without apparent spin-density wave anomalies. The transitions to the zero resistance state have widths of less than 4 K.

Although all of the samples in Table [I](#page-1-0) have the same starting composition, small variations in synthesis pressure and temperature result in a dispersion in *x* around the nominal 0.1 value for the HoFeAs $O_{1-x}F_x$ phase and corresponding variations in superconducting properties. T_c increases to a maximum value, T_c (max), at the upper solubility limit of *x* in $RFeAsO_{1-x}F_x$ systems,⁷ and this is consistent with the observation that the superconducting phases in samples 1, 3, and 4, which are heated at high temperatures or for longer times and so are likely to have a slightly lower F content, have lower T_c 's (average 32.1 K) than the other three samples, made under nominally identical "optimum" conditions, which have average $T_c = 34.8$ K. Sample 6 shows the highest T_c = 36.2 K and the lowest proportion of the HoFeAsO_{1−*x*}F_{*x}*</sub> phase and a correspondingly low diamagnetic volume fraction. This demonstrates that the sample is at the upper limit of the superconducting composition range and so gives a realistic T_c (max) for the HoFeAsO_{1−*x*}F_{*x*} system.

FIG. 2. Fitted x-ray diffraction profile for HoFeAsO $_{0.9}F_{0.1}$ (sample 5) at room temperature. The Bragg markers (from top to bottom) are for the minority phases, $Ho₂O₃$ and HoAs, and for HoFeAs $O_{0.9}F_{0.1}$.

Although the doping values *x* for the high-pressure $RFeAsO_{1-x}F_x$ samples are not known precisely, comparing ensembles of samples with similar phase purities made under similar conditions reveals a clear suppression of superconductivity by lattice effects for heavier *R*. For example, all of our TbFeAsO_{1−*x*}F_{*x*} superconductors have higher T_c 's (five TbFeAsO_{1−*x*}F_{*x*} samples, $T_c = 45-51$ K) than all of the HoFeAsO_{1-*x*}F_{*x*} materials (in Table [I](#page-1-0)). The T_c (max) values of 51, 45, and 36 K for $RFeAsO_{1−x}F_x$ with $R=Th$, Dy, and Ho, respectively, thus represent the trend correctly.

Figure [4](#page-2-0) shows a plot of the maximum critical temperatures, T_c (max), against unit-cell volume for many reported $RFeAsO_{1-x}F_x$ and $RFeAsO_{1-\delta}$ systems and our above materials. T_c (max) rises slowly as cell volume decreases for *R* =La to Pr and then shows a broad maximum, between *R* =Pr and Tb in the $RFeAsO_{1-x}F_x$ materials, before falling rapidly as *R* changes from Tb to Dy to Ho. This trend is not seen in the reported *RFeAsO*_{1−*x*} superconductors, where T_c (max) remains approximately constant,^{14,[15](#page-3-12)} apparently because they have larger cell volumes than their $RFeAsO_{1-x}F_x$ analogs (see Fig. [4](#page-2-0)).

The size of the R^{3+} cation tunes the electronic properties through variations in the geometry of the FeAs slab. A trend between the As-Fe-As (or equivalent Fe-As-Fe) angle and T_c has been reported for the early *R* materials.¹⁶ The upper panel of Fig. [4](#page-2-0) shows representative reported values for optimal *R*FeAsO_{1−*x*}F_{*x*} superconductors including our *R*=Tb, Dy, and Ho materials. This demonstrates that the angle decreases monotonically with *R* size and so does not show a universal correlation with T_c (max). The T_c (max) variation in the *RFeAsO*_{1−*x*}F_{*x*} series is described by a simple cos(ϕ $-\phi_0$) function, shown in Fig. [4,](#page-2-0) where the value of the As-

FIG. 3. Superconductivity measurements for $HoFeAs_{0.9}F_{0.1}$; (a) ac magnetic volume susceptibility for the six samples; (b) resistivities for samples 4 and 6.

FIG. 4. Variation in Fe-As-Fe angle ϕ (upper panel) and superconducting T_c (lower panel) with unit-cell volume for different $RFeAsO_{1-x}F_x$ (circles) (Refs. [19,](#page-3-16) [22,](#page-3-19) [5,](#page-3-5) [7,](#page-3-10) and [12](#page-3-8)) and $RFeAsO_{1-\delta}$ (triangles) (Refs. [14](#page-3-11) and [15](#page-3-12)). T_c (max) points are shown as filled symbols. The fit of equation $T_c(\text{max}) = T_c(\text{max})_0 \cos A(\phi - \phi_0)$ with parameters $T_c(\text{max})_0 = 56 \text{ K}$, $A = 0.03$, and $\phi_0 = 110.6^{\circ}$ is also shown. dT_c/dV values are derived from the data for suboptimally doped materials (open symbols) in the $R = La$ (Ref. [19](#page-3-16)), Sm (Ref. [7](#page-3-10)), and Ho (this Brief Report) systems.

Fe-As angle corresponding to the global maximum T_c , ϕ_{max} = 110.6°, is close to the ideal 109.5° value for a regular FeAs₄ tetrahedron. All five of the Fe 3*d* bands are partially occupied and contribute to the Fermi surface of the iron arsenide superconductors through hybridization with As 4*s* and $4p$ states.^{[17](#page-3-14)} Decreasing the tetrahedral angle through 109.5° marks the crossover from tetragonal compression to elongation of the $FeAs₄$ tetrahedra. In a crystal-field model, this reverses the splittings of the t_2 and e d-orbital sets and so a significant crossover in the real electronic structure is likely to occur near 109.5°.

Evidence for the above crossover also comes from a discovered change in the sign of the compositional dT_c/dV near optimum doping in the *R*FeAsO_{1−*x*}F_{*x*} systems.¹⁸ The unit-cell parameters and volume for the six HoFeAsO_{1−*x*}F_{*x*} samples in Table [I](#page-1-0) show a positive correlation with T_c (Fig. [5](#page-2-1)), in contrast to early $R = La$ (Ref. [19](#page-3-16)) and Sm (Ref. [7](#page-3-10)) analogs, where lattice parameters and volume decease with increasing T_c . The T_c , *V* points for near-optimally doped $R = La$, Sm, and Ho *RFeAs*O_{1−*x*}F_{*x*} superconductors are shown in Fig. [4](#page-2-0) together with the derived dT_c/dV values. dT_c/dV for a single $RFeAsO_{1-x}F_x$ system follows the overall trend in dT_c (max)/dV for different *R*'s, changing from a negative value at large $R = La$ to a small positive slope at $R = Ho$.

The compositional dT_c/dV for a given $RFeAsO_{1-x}F_x$ system reflects two competing effects of variations in the fluoride content *x* on the lattice volume. F^{$-$} is slightly smaller than O^{2-} so the anion substitution effect gives a negative

FIG. 5. Variations in T_c with the tetragonal unit-cell parameters and volume for the six HoFeAsO_{1−*x*}F_{*x*} samples in Table [I.](#page-1-0)

contribution to the compositional dT_c/dV , independent of *R*. The concomitant effect of doping electrons into the Fe *d* bands tends to expand the lattice (and increase T_c), but the magnitude of this positive dT_c/dV term depends on the nature of the bands at the Fermi surface. The observed shift from negative to positive dT_c/dV as *R* changes from La to Ho shows that the decreasing size of the R^{3+} cation leads to significant changes in the Fermi surface, with volumeexpanding (antibonding) bands more prominent for smaller *R*. Calculations have confirmed that the electronic structure near the Fermi level is sensitive to such small changes in the As *z* coordinate (equivalent to changing the Fe-As-Fe angle).^{[20](#page-3-17)} Small changes in the contributions of the d bands are likely to be particularly important in a multigap scenario for superconductivity, as evidenced in gap measurements of TbFeAsO_{0.9}F_{0.1} and other iron arsenide materials.²¹

In summary, our analysis of multiple samples of $RFeAsO_{1-x}F_x$ ($R = Tb$, Dy, and Ho) superconductors demonstrates that the maximum critical temperature falls from 51 K for $R = Tb$ to 36 K for the previously unreported Ho analog. Hence, the effect on the lattice of substituting smaller late rare earths in the $RFeAsO_{1-x}F_x$ lattice suppresses superconductivity. This lattice control appears to be through tuning of the interatomic angles in the FeAs layer, with the optimum angle being 110.6°, near the ideal tetrahedral value. The compositional dT_c/dV changes sign around the optimum angle evidencing significant changes in the Fermi surface. It appears difficult to increase the critical temperatures above 56 K in 1111 type iron arsenide materials through tuning lattice effects, although the possibility of higher T_c 's in other structure types remains open.

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